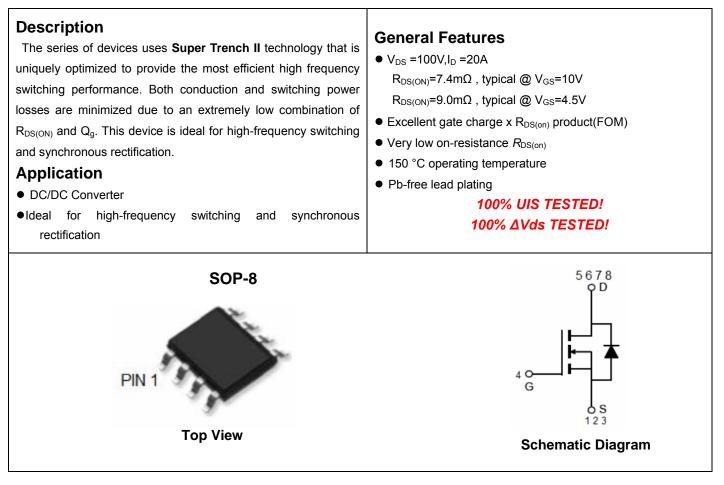


## NCE N-Channel Super Trench II Power MOSFET



#### Package Marking and Ordering Information

| Device Marking | Device       | Device Package | Reel Size | Tape width | Quantity   |
|----------------|--------------|----------------|-----------|------------|------------|
| NCEP082N10AS   | NCEP082N10AS | SOP-8          | Ø330mm    | 12mm       | 4000 units |

#### Absolute Maximum Ratings (Tc=25℃unless otherwise noted)

| Parameter  | Symbol                           | Limit      | Unit |
|--|----------------------------------|------------|------|
| Drain-Source Voltage                             | Vds                              | 100        | V    |
| Gate-Source Voltage                              | Vgs                              | ±20        | V    |
| Drain Current-Continuous                         | Ι <sub>D</sub>                   | 20         | А    |
| Drain Current-Continuous(T <sub>C</sub> =100°C)  | I <sub>D</sub> (100℃)            | 14.1       | А    |
| Pulsed Drain Current                             | I <sub>DM</sub>                  | 80         | А    |
| Maximum Power Dissipation                        | PD                               | 3.5        | W    |
| Single pulse avalanche energy (Note 5)           | E <sub>AS</sub>                  | 300        | mJ   |
| Operating Junction and Storage Temperature Range | T <sub>J</sub> ,T <sub>STG</sub> | -55 To 150 | °C   |

#### **Thermal Characteristic**

| Thermal Resistance.Junction-to-Ambient <sup>(Note 2)</sup> | Relia  | 36 | °C/W |
|--|--------|----|------|
|  | 1 VOJA | 00 | 0/11 |



### Electrical Characteristics (T<sub>c</sub>=25<sup>°</sup>C unless otherwise noted)

| Parameter                          | Parameter Symbol Condition |   | Min | Тур  | Max  | Unit |
|------------------------------------|----------------------------|---|-----|------|------|------|
| Off Characteristics                |                            |   | ·   |      |      |      |
| Drain-Source Breakdown Voltage     | BV <sub>DSS</sub>          | V <sub>GS</sub> =0V I <sub>D</sub> =250µA                                       | 100 |      | -    | V    |
| Zero Gate Voltage Drain Current    | I <sub>DSS</sub>           | V <sub>DS</sub> =100V,V <sub>GS</sub> =0V                                       | -   | -    | 1    | μA   |
| Gate-Body Leakage Current          | I <sub>GSS</sub>           | $V_{GS}$ =±20V, $V_{DS}$ =0V  | -   | -    | ±100 | nA   |
| On Characteristics (Note 3)        |                            |   | •   |      |      |      |
| Gate Threshold Voltage             | V <sub>GS(th)</sub>        | $V_{DS}=V_{GS}$ , $I_{D}=250\mu A$  | 1.2 | 1.7  | 2.2  | V    |
| Drain Course On State Desistance   | P                          | $V_{GS}$ =10V, $I_{D}$ =10A   | -   | 7.4  | 8.2  | mΩ   |
| Drain-Source On-State Resistance   | R <sub>DS(ON)</sub>        | $V_{GS}$ =4.5V, I <sub>D</sub> =10A   | -   | 9.0  | 11.0 | mΩ   |
| Forward Transconductance           | <b>g</b> fs                | V <sub>DS</sub> =5V,I <sub>D</sub> =45A   |     | 60   | -    | S    |
| Dynamic Characteristics (Note4)    |                            |   | ·   |      |      |      |
| Input Capacitance                  | C <sub>lss</sub>           |   | -   | 5580 | -    | PF   |
| Output Capacitance                 | C <sub>oss</sub>           | V <sub>DS</sub> =50V,V <sub>GS</sub> =0V,<br>F=1.0MHz                           |     | 360  | -    | PF   |
| Reverse Transfer Capacitance       | C <sub>rss</sub>           |   |     | 15   | -    | PF   |
| Switching Characteristics (Note 4) |                            |   | •   |      |      |      |
| Turn-on Delay Time                 | t <sub>d(on)</sub>         |   | -   | 17   | -    | nS   |
| Turn-on Rise Time                  | tr                         | $V_{DD}$ =50V,I <sub>D</sub> =10A<br>$V_{GS}$ =10V,R <sub>G</sub> =1.6 $\Omega$ |     | 10.5 | -    | nS   |
| Turn-Off Delay Time                | t <sub>d(off)</sub>        |   |     | 40   | -    | nS   |
| Turn-Off Fall Time                 | t <sub>f</sub>             |   |     | 7    | -    | nS   |
| Total Gate Charge                  | Qg                         | )/ _===0)// =====0.0  | -   | 83   | -    | nC   |
| Gate-Source Charge                 | Q <sub>gs</sub>            | V <sub>DS</sub> =50V,I <sub>D</sub> =10A,<br>V <sub>GS</sub> =10V               |     | 13   |      | nC   |
| Gate-Drain Charge                  | Q <sub>gd</sub>            |   |     | 15   |      | nC   |
| Drain-Source Diode Characteristics |                            |   | •   |      |      |      |
| Diode Forward Voltage (Note 3)     | V <sub>SD</sub>            | V <sub>GS</sub> =0V,I <sub>S</sub> =10A   | -   |      | 1.2  | V    |
| Diode Forward Current (Note 2)     | Is                         |   | -   | -    | 20   | Α    |
| Reverse Recovery Time              | t <sub>rr</sub>            | $T_{J} = 25^{\circ}C, I_{F} = 10A$  | -   | 68   | -    | nS   |
| Reverse Recovery Charge            | Qrr                        | di/dt = 100A/µs <sup>(Note3)</sup>  | -   | 110  | -    | nC   |
|                                    |                            |   |     |      |      |      |

#### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t  $\leq$  10 sec.

3. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25  $^\circ C$  ,V\_DD=40V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$ 



V<sub>GS</sub>=4.5V I<sub>D</sub>=10A

125

60

25° C

8.0

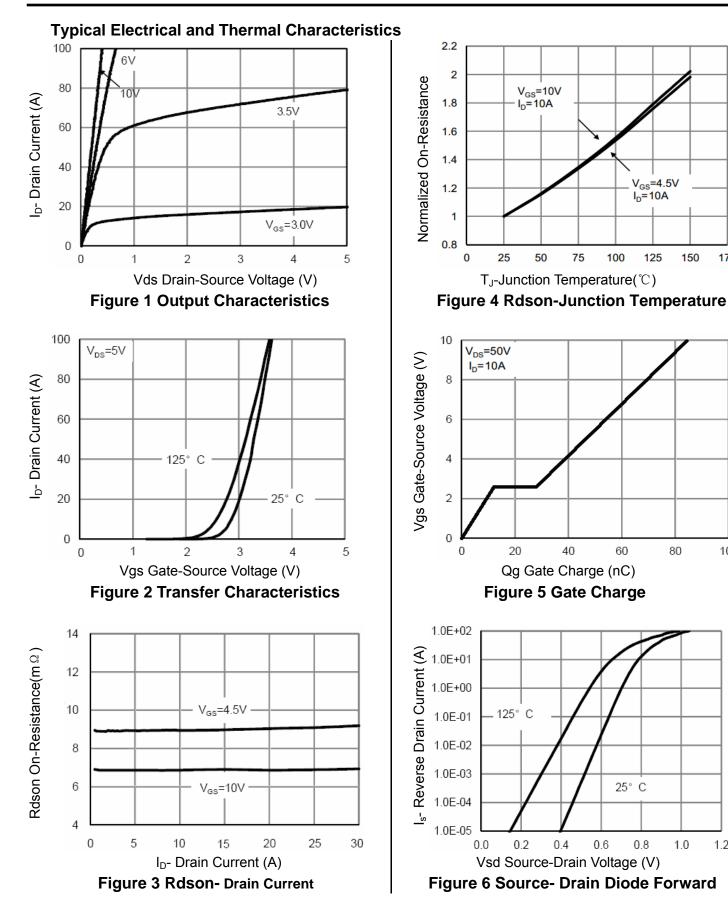
1.0

80

100

150

175



1.2



# NCEP082N10AS

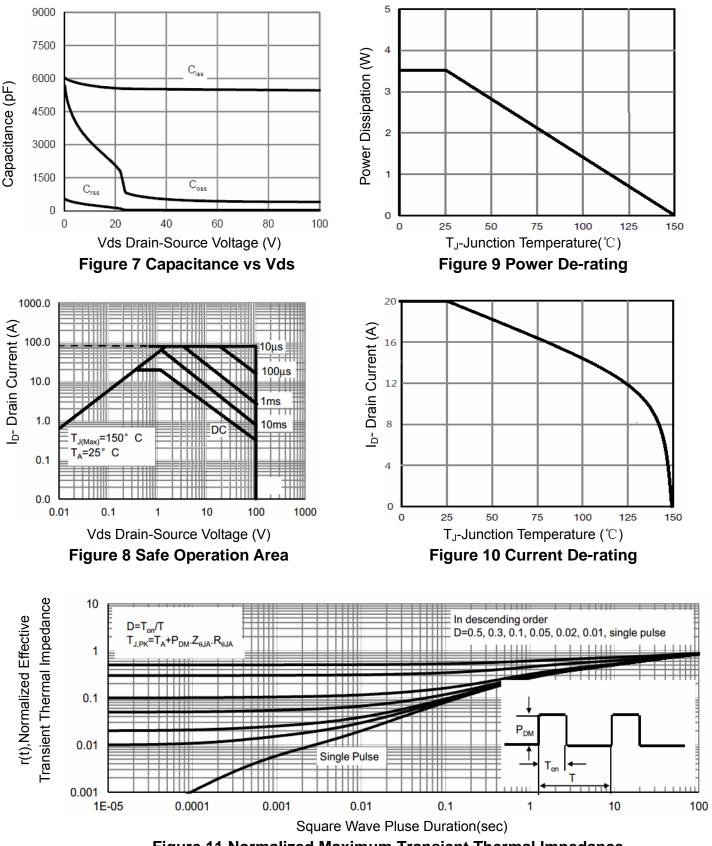
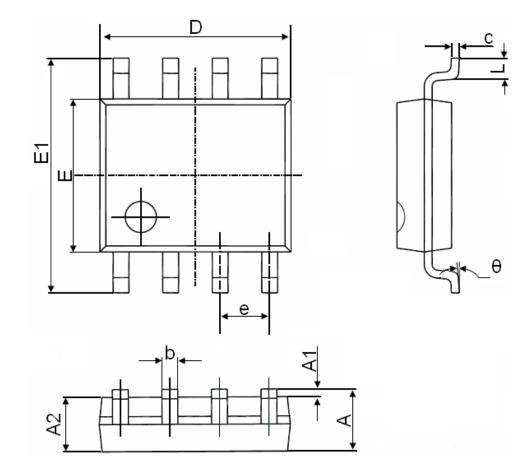


Figure 11 Normalized Maximum Transient Thermal Impedance



# SOP-8 Package Information



| Symbol | Dimensions I | n Millimeters | Dimensions In Inches |       |  |
|--------|--------------|---------------|----------------------|-------|--|
| Symbol | Min.         | Max.          | Min.                 | Max.  |  |
| A      | 1.350        | 1.750         | 0.053                | 0.069 |  |
| A1     | 0.100        | 0.250         | 0.004                | 0.010 |  |
| A2     | 1.350        | 1.550         | 0.053                | 0.061 |  |
| b      | 0.330        | 0.510         | 0.013                | 0.020 |  |
| с      | 0.170        | 0.250         | 0.006                | 0.010 |  |
| D      | 4.700        | 5.100         | 0.185                | 0.200 |  |
| E      | 3.800        | 4.000         | 0.150                | 0.157 |  |
| E1     | 5.800        | 6.200         | 0.228                | 0.244 |  |
| е      | 1.270(BSC)   |               | 0.050(BSC)           |       |  |
| L      | 0.400        | 1.270         | 0.016                | 0.050 |  |
| θ      | 0°           | 8°            | 0°                   | 8°    |  |



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